

Data sheet acquired from Harris Semiconductor SCHS170B

November 1997 - Revised October 2003

High-Speed CMOS Logic Dual 4-Input Multiplexer

Features

- Common Select Inputs
- Separate Output-Enable Inputs
- Three-State Outputs
- Fanout (Over Temperature Range)
 - Standard Outputs......10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_{I} \leq 1 \mu A$ at $V_{OL}, \, V_{OH}$

Description

The CD74HC253 and CD74HCT253 are dual 4-to-1 line selector/multiplexers having three-state outputs. One of four sources for each section is selected by the common select inputs, S0 and S1. When the output enable $(\overline{10E}, \overline{20E})$ is HIGH, the output is in the high-impedance state.

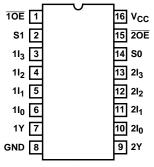
Ordering Information

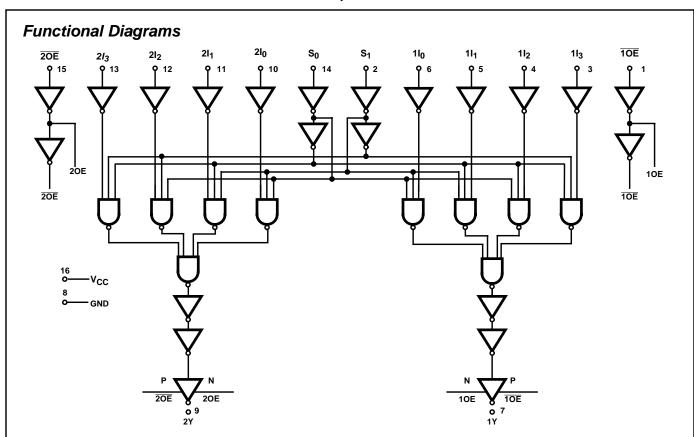
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD74HC253E	-55 to 125	16 Ld PDIP
CD74HC253M	-55 to 125	16 Ld SOIC
CD74HC253MT	-55 to 125	16 Ld SOIC
CD74HC253M96	-55 to 125	16 Ld SOIC
CD74HCT253E	-55 to 125	16 Ld PDIP
CD74HCT253M	-55 to 125	16 Ld SOIC
CD74HCT253MT	-55 to 125	16 Ld SOIC
CD74HCT253M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD74HC253, CD74HCT253 (PDIP, SOIC) TOP VIEW





TRUTH TABLE

	INPUTS te 1)		DATA I	NPUTS		OUTPUT ENABLE	ОИТРИТ
S1	S0	I ₀	I ₁	l ₂	l ₃	ŌĒ	Y
Х	Х	Х	Х	Х	Х	Н	Z
L	L	L	Х	Х	Х	L	L
L	L	Н	Х	Х	Х	L	Н
L	Н	Х	L	Х	Х	L	L
L	Н	Х	Н	Х	Х	L	Н
Н	L	Х	Х	L	Х	L	L
Н	L	Х	Х	Н	Х	L	Н
Н	Н	Х	Х	Х	L	L	L
Н	Н	Х	Х	Х	Н	L	Н

H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High Impedance (Off). NOTE:

1. Select inputs S1 and S0 are common to both sections.

Absolute Maximum Ratings

DC Supply Voltage, V $_{CC}$... -0.5V to 7V DC Input Diode Current, I $_{IK}$ For V $_{I}$ < -0.5V or V $_{I}$ > V $_{CC}$ + 0.5V ± 20 mA DC Output Diode Current, I $_{OK}$ For V $_{O}$ < -0.5V or V $_{O}$ > V $_{CC}$ + 0.5V ± 20 mA DC Drain Current, per Output, I $_{O}$ For -0.5V < V $_{O}$ < V $_{CC}$ + 0.5V ± 35 mA DC Output Source or Sink Current per Output Pin, I $_{O}$ For V $_{O}$ > -0.5V or V $_{O}$ < V $_{CC}$ + 0.5V ± 25 mA DC V $_{CC}$ or Ground Current, I $_{CC}$... ± 50 mA

Thermal Information

Thermal Resistance (Typical, Note 2) θ_{JA} (oC/W)
E (PDIP) Package	67
	73
Maximum Junction Temperature	150°C
Maximum Storage Temperature Range65°C to	150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T _A 55°C to 125°C Supply Voltage Range, V _{CC}
HC Types2V to 6V
• •
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TES CONDI		V _{CC}		25°C		-40°C T	O 85°C	-55°C TO 125°C																					
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS																			
HC TYPES																															
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V																			
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V																			
				6	4.2	-	-	4.2	-	4.2	-	V																			
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V																			
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V																			
				6	-	-	1.8	-	1.8	-	1.8	V																			
High Level Output	utput V _{OH} V _{IH} or V _I	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V																			
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V																			
Owied Edda			-0.02	6	5.9	-	-	5.9	-	5.9	-	V																			
High Level Output	7			-	-	-	-	-	-	-	-	-	V																		
Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V																			
TTE Education			-7.8	6	5.48	-	-	5.34	-	5.2	-	V																			
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V																			
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V																			
Owied Edda			0.02	6	-	-	0.1	-	0.1	-	0.1	V																			
Low Level Output												,	Ī	,								-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-6	4.5	-	-	0.26	-	0.33	-	0.4	V																			
	<u> </u>		-7.8	6	-	-	0.26	-	0.33	-	0.4	V																			
Input Leakage Current	Ι _Ι	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА																			

DC Electrical Specifications (Continued)

	TEST CONDITIONS VCC 25°C			-40°C 1	O 85°C	-55°C T	O 125°C					
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μА
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	I _{CC}	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5	-	±10	μА

NOTE:

3. For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
1l _O - 1l ₃ , 2l _O -2l ₃	0.4
1E _O , 2E _O , S ₀ , S ₁	1

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

Switching Specifications Input t_r , $t_f = 6ns$

		TEST	V _{CC}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-										
Propagation Delay	t _{PLH,}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
Select to Outputs	^t PHL		4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns

Switching Specifications Input t_r , t_f = 6ns (Continued)

		TEST	v _{cc}		25°C			С ТО °С		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Data to Outputs	t _{PLH,}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
	t _{PHL}		4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Disable Delay Times	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	150	-	190	-	225	ns
		C _L = 50pF	4.5	-	-	30	-	38	-	45	ns
		CL = 15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	26	-	33	-	38	ns
Enable Delay Times	t _{PZH} ,	C _L = 50pF	2	-	-	110	-	140	-	165	ns
	t _{PZL}	CL = 50pF	4.5	-	-	22	-	28	-	33	ns
		CL = 15pF	5	-	9	-	-	-	-	-	ns
		CL = 50pF	6	-	-	19	-	24	-	28	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	60	-	75	-	90	ns
			4.5	-	-	12	-	15	-	18	ns
			6	-	-	10	-	13	-	15	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Three-State Output Capacitance	СО	-	-	-	-	20	-	20	-	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	46	-	-	-	=	-	pF
HCT TYPES					•						
Propagation Delay Select to Outputs	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	40	-	50	-	60	ns
		C _L =15pF	5	-	16	-	-		-	-	ns
Data to Outputs	t _{PLH} ,	C _L = 50pF	4.5	-	-	38	-	48	-	57	ns
	tPHL	C _L =15pF	5	-	16	-	-	-	-	-	ns
Disable Delay Times	t _{PLH} ,	C _L = 50pF	4.5	-		30	-	38	-	45	ns
	t _{PHL}	C _L =15pF	5	-	12	-	-	-	-	-	ns
Enable Delay Times	t _{PZH} ,	C _L = 50pF	4.5	-	-	30	-	38	-	45	ns
	t _{PZL}	C _L =15pF	5	-	12	-	-	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	12	-	15	-	18	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Three-State Output Capacitance	CO	-	-	-	-	20	-	20	-	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	52	1	ı	-	-	-	pF

NOTES:

^{4.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per multiplexer.

^{5.} $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

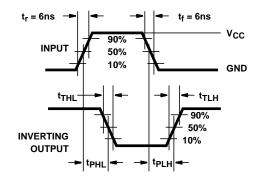


FIGURE 1. HC AND HCT TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

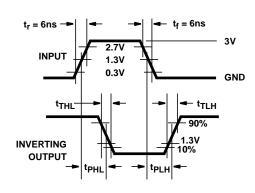


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

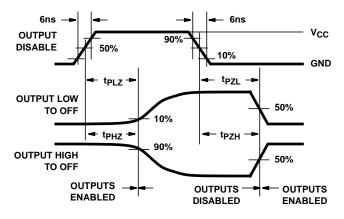


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

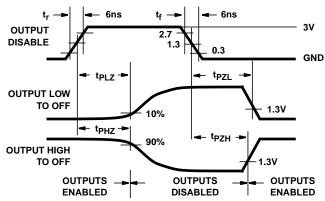
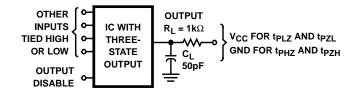


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(-)		J		,	(=)	(6)	(=)		(32)	
CD74HC253E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC253E	Samples
CD74HC253M	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC253M	Samples
CD74HC253MT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC253M	Samples
CD74HCT253E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT253E	Samples
CD74HCT253M	OBSOLETI	E SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT253M	
CD74HCT253M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT253M	Samples
CD74HCT253MT	OBSOLETI	E SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT253M	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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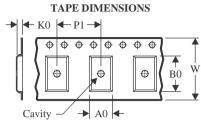
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

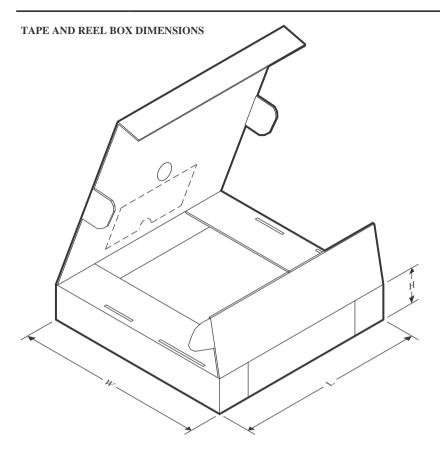


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HCT253M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ı	CD74HCT253M96	SOIC	D	16	2500	340.5	336.1	32.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC253E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC253E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC253M	D	SOIC	16	40	507	8	3940	4.32
CD74HCT253E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT253E	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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